

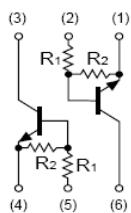
General purpose transistors (dual transistors)

FEATURES

- Two DTC124E chip in a package
- Mounting possible with SOT-363 automatic mounting machines.
- Transistor elements are independent, eliminating interference.
- Mounting cost and area be cut in half.

Marking: H1

Equivalent circuit



$$R_1 = R_2 = 22\text{ k}\Omega$$

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits		Unit
Supply voltage	V _{CC}	50		V
Input voltage	V _{IN}	-10~40		V
Output current	I _O	30		mA
	I _{C(MAX)}	100		
Power dissipation	P _d	150		mW
Junction temperature	T _j	150		°C
Storage temperature	T _{stg}	-55~150		°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input voltage	V _{I(off)}			0.5	V	V _{CC} =5V, I _O =100μA
	V _{I(on)}	3				V _O =0.2V, I _O =5mA
Output voltage	V _{O(on)}		0.1	0.3	V	I _O /I _I =10mA/0.5mA
Input current	I _I			0.36	mA	V _I =5V
Output current	I _{O(off)}			0.5	μA	V _{CC} =50V, V _I =0
DC current gain	G _I	56				V _O =5V, I _O =5mA
Input resistance	R ₁	15.4	22	28.6	KΩ	-
Resistance ratio	R ₂ /R ₁	0.8	1	1.2		-
Transition frequency	f _T		250		MHz	V _{CE} =10V, I _E =5mA, f=100MHz